

## SCS208AG SiC Schottky Barrier Diode

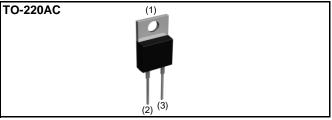
V <sub>R</sub>	650V
I <sub>F</sub>	8A
Q <sub>C</sub>	13nC

#### Features

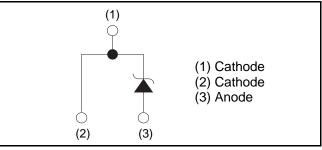
Construction

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

#### Outline



#### Inner circuit



#### Packaging specifications

	Packaging	Tube
	Reel size (mm)	-
Tuno	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	С
	Marking	SCS208AG

### • Absolute maximum ratings (Ti = $25^{\circ}$ C)

Silicon carbide epitaxial planer type

Parameter	Symbol	Value	Unit	
Reverse voltage (repetitive peak)	V <sub>RM</sub>	650	V	
Reverse voltage (DC)	V <sub>R</sub>	650	V	
Continuous forward current	١ <sub>F</sub>	8* <sup>1</sup>	А	
		31* <sup>2</sup>	А	
Surge no repetitive forward current	I <sub>FSM</sub>	118* <sup>3</sup>	А	
		25* <sup>4</sup>	А	
Repetitive peak forward current	I <sub>FRM</sub>	35* <sup>5</sup>	А	
Total power disspation	P <sub>D</sub>	68* <sup>6</sup>	W	
Junction temperature	Тј	175	°C	
Range of storage temperature	Tstg	-55 to +175	°C	

\*1 Tc=139°C \*2 PW=8.3ms sinusoidal, Tj=25°C \*3 PW=10µs square, Tj=25°C

\*4 PW=8.3ms sinusoidal, Tj=150°C \*5 Tc=100°C, Tj=150°C, Duty cycle=10% \*6 Tc=25°C

#### •Electrical characteristics (Tj = 25°C)

Parameter	Symbol	Conditions	Values			الم:4
Parameter			Min.	Тур.	Max.	Unit
DC blocking voltage	$V_{DC}$	I <sub>R</sub> =0.16mA	600	-	-	V
	V <sub>F</sub>	I <sub>F</sub> =8A,Tj=25°C	-	1.35	1.55	V
Forward voltage		I <sub>F</sub> =8A,Tj=150°C	-	1.55	-	V
		I <sub>F</sub> =8A,Tj=175°C	-	1.63	-	V
Reverse current	I <sub>R</sub>	V <sub>R</sub> =600V,Tj=25°C	-	1.6	160	μA
		V <sub>R</sub> =600V,Tj=150°C	-	24	-	μA
		V <sub>R</sub> =600V,Tj=175°C	-	56	-	μA
Total capacitance	С	V <sub>R</sub> =1V,f=1MHz	-	291	-	pF
		V <sub>R</sub> =600V,f=1MHz	-	30	-	pF
Total capacitive charge	Qc	V <sub>R</sub> =400V,di/dt=350A/μs	-	13	-	nC
Switching time	tc	V <sub>R</sub> =400V,di/dt=350A/μs	-	13	-	ns

#### •Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Unit
Thermal resistance	R <sub>th(j-c)</sub>	-	-	1.9	2.2	°C/W

#### Electrical characteristic curves

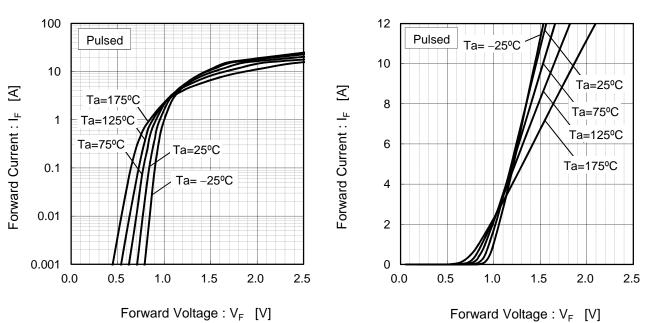
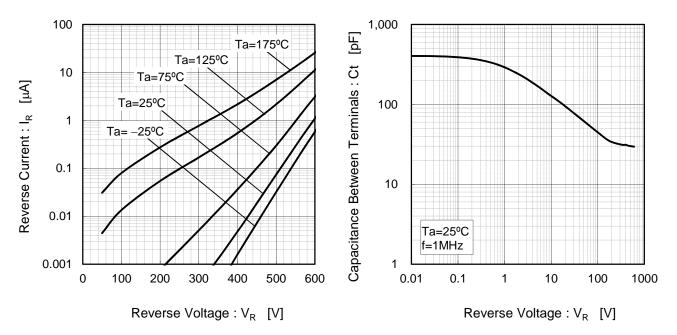


Fig.1 V<sub>F</sub> - I<sub>F</sub> Characteristics

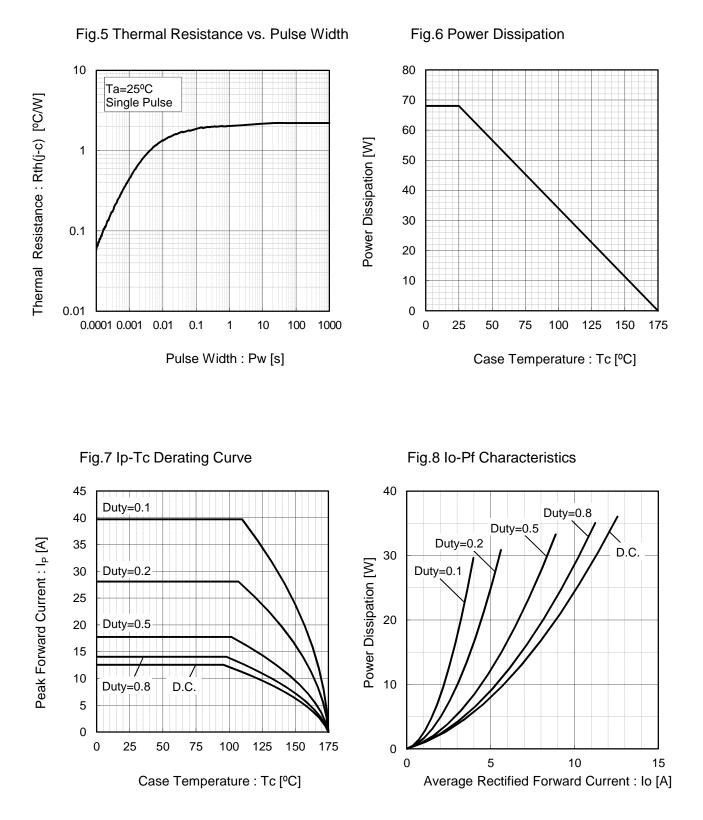
Fig.3  $V_R$  -  $I_R$  Characteristics

Fig.4 V<sub>R</sub>-Ct Characteristics

Fig.2  $V_F$  -  $I_F$  Characteristics

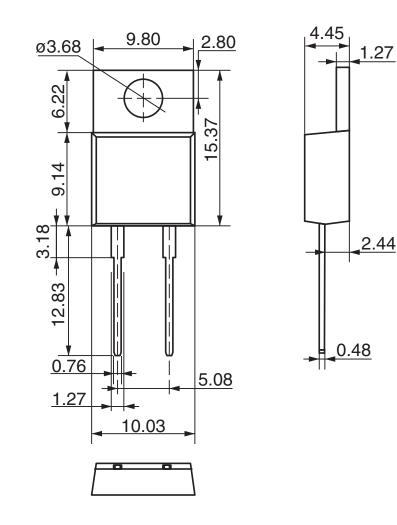


#### •Electrical characteristic curves



#### •Dimensions (Unit : mm)

#### **TO-220AC**



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